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DATE:	October 23, 2005	PAGES:	<u>9 (nine) w/cover</u>
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Message**Docket No. GS 162 D1**

Please see attached: Amendment After Final Rejection

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Patent
10/673,889

I hereby certify that this document and any documents referenced herein have been transmitted via facsimile to the Commission for Patents, at (571) 273-8300 on October 23, 2005.

Date:

10/23/05
Karin L. Williams**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Richard A. Blanchard
Serial No.: 10/673,889
Filed: September 29, 2003
Title: High Voltage Power MOSFET Having Low On-Resistance
Art Unit: 2814
Examiner: Thao X. Le
Docket No.: GS 162 Div.
Confirmation No.: 1992

VIA FACSIMILE: 571-273-8300

Commissioner for Patents
PO Box 1450
Alexandria, VA 22313-1450

AMENDMENT AFTER FINAL REJECTION

Sir:

In response to the Office Action dated July 26, 2005, please amend the above-identified application as follows. In addition, any deficiencies may be charged to deposit account No. 50-1047.